



DMT3006LFVQ

### 30V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (Type UX)

# **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C		
30V	$7m\Omega$ @ $V_{GS} = 10V$	60A		
307	$11m\Omega @ V_{GS} = 4.5V$	OUA		

# **Description**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# **Applications**

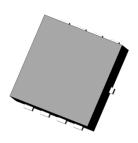
- Power Management Functions
- Analog Switch

### **Features**

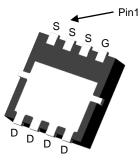
- Low R<sub>DS(ON)</sub> Ensures On-State Losses are Minimized
- 100% Unclamped Inductive Switching (Test in Production) Ensures More Reliable and Robust End Application
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### **Mechanical Data**

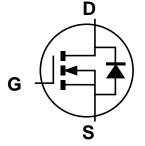
- Case: PowerDI<sup>®</sup>3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 <sup>(3)</sup>
- Weight: 0.03 grams (Approximate)







**Bottom View** 



**Equivalent Circuit** 

## Ordering Information (Note 5)

h-		
Part Number	Case	Packaging
DMT3006LFVQ-7	PowerDI3333-8 (Type UX)	2,000/Tape & Reel
DMT3006LFVQ-13	PowerDI3333-8 (Type UX)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

# **Marking Information**



FV6 = Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 18 = 2018)

WW = Week Code (01 to 53)



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	30	V
Gate-Source Voltage			$V_{GSS}$	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 8)	Steady State	$T_C = +25$ °C $T_C = +70$ °C	I <sub>D</sub>	60 45	А
Maximum Body Diode Forward Current (Note 8)	Is	2	Α		
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%	I <sub>DM</sub>	90	Α		
Pulsed Drain Body Diode Forward Current (380µs Pulse, Duty Cycle = 1%)			I <sub>SM</sub>	90	Α
Avalanche Current (L = 0.1mH) (Note 9)			I <sub>AS</sub>	24	Α
Avalanche Energy (L = 0.1mH) (Note 9)			E <sub>AS</sub>	29	mJ

# Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		$P_{D}$	1.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	130	°C/W
Total Power Dissipation (Note 7)		$P_{D}$	2.0	W
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	$R_{ heta JA}$	63	°C/W
Thermal Resistance, Junction to Case (Note 8)	$R_{\theta JC}$	2.9	C/VV	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C

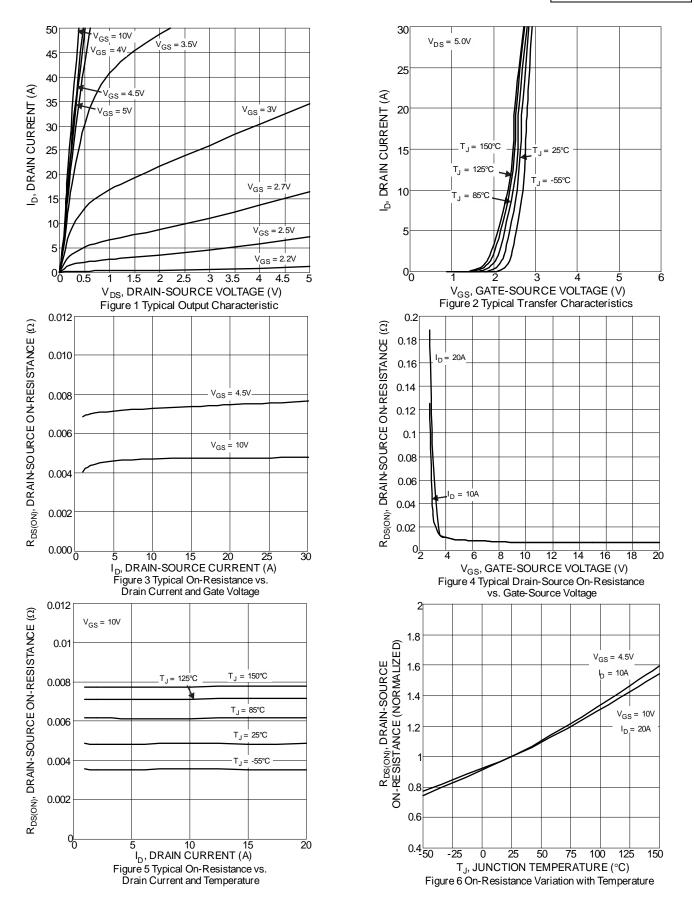
# **Electrical Characteristics** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	$BV_{DSS}$	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 24V$ , $V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = +20V, V_{DS} = 0V$ $V_{GS} = -16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0		3.0	٧	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
Static Drain-Source On-Resistance			5.6	7	mΩ	$V_{GS} = 10V, I_D = 9.0A$	
Static Dialii-Source Off-Resistance	R <sub>DS(ON)</sub>		8.0	11	11122	$V_{GS} = 4.5V, I_D = 8.5A$	
Diode Forward Voltage	$V_{SD}$	_	0.70	1.2	٧	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	C <sub>iss</sub>	_	1,155	_		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	456		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	72	_			
Gate Resistance	$R_g$	_	1.6	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$	_	8.4	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_g$	_	16.7	_			
Gate-Source Charge	$Q_{gs}$	_	2.2		IIC	$V_{DD} = 15V, I_{D} = 9A$	
Gate-Drain Charge	$Q_{gd}$	_	3.5	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	3.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	5.5	_		$V_{DD} = 15V, V_{GS} = 10V,$ $R_G = 3\Omega, I_D = 9A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	13.5	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	4.6	_			
Reverse Recovery Time	t <sub>RR</sub>	_	19.3	_	ns	1 4 5 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4 4	
Reverse Recovery Charge	Q <sub>RR</sub>	_	8.6	_	nC	$I_F = 1.5A$ , di/dt = 100A/ $\mu$ s	

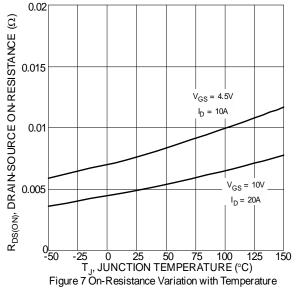
Notes

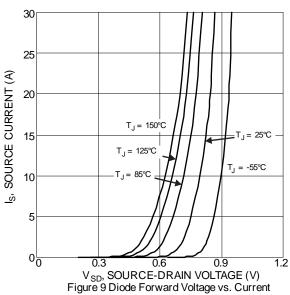
- 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
- 8. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 9. IAS and EAS ratings are based on low frequency and duty cycles to keep  $T_J = +25$ °C.
- 10. Short duration pulse test used to minimize self-heating effect.
- 11. Guaranteed by design. Not subject to product testing.

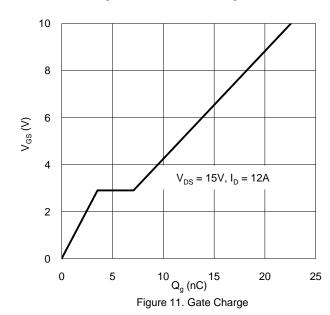












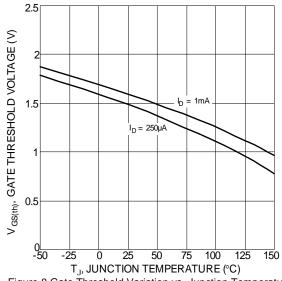
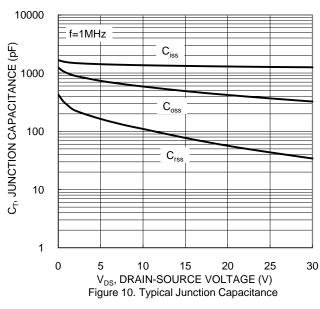
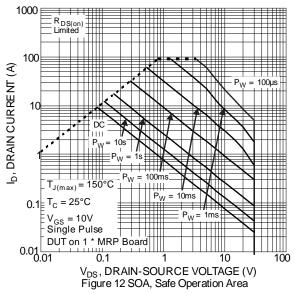


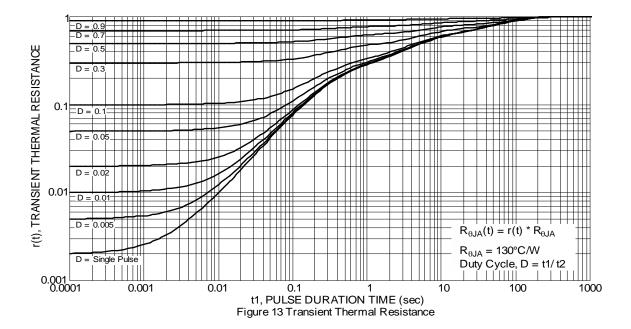
Figure 8 Gate Threshold Variation vs. Junction Temperature





May 2018



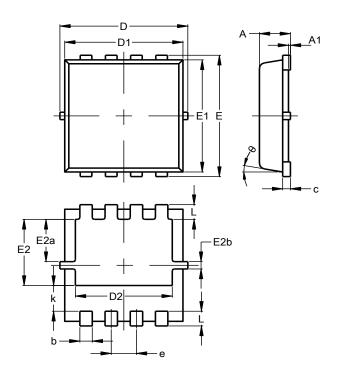




# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

# PowerDI3333-8 (Type UX)

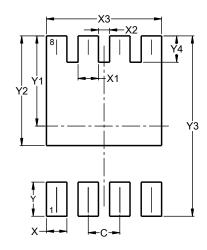


PowerDI3333-8						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05				
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E2a	0.95	1.35	1.15			
E2b	0.10	0.30	0.20			
е	0.65 BSC					
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (Type UX)



Dimensions	Value (in mm)		
С	0.650		
Х	0.420		
X1	0.420		
X2	0.230		
Х3	2.370		
Υ	0.700		
Y1	1.850		
Y2	2.250		
Y3	3.700		
Y4	0.540		



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